DEC 27 2006 W

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of:

Geum-Jong BAE, et al

Art Unit:

2814

Serial No. 10/659,384

(Division of Serial No. 10/274,035

filed October 21, 2002)

Examiner:

Hoai V. Pham

Filed: September 11, 2003

Confirmation No.: 3795

For:

MOS TRANSISTOR HAVING A T-SHAPED

GATE ELECTRODE AND METHOD FOR

FABRICATING THE SAME

Attorney Docket No.: 239/169 DIV

AMENDMENT UNDER 37 C.F.R. § 1.111

Mail Stop: Amendments Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

INTRODUCTORY COMMENTS

In response to the Office action mailed September 27, 2006, the following amendments and remarks are respectfully submitted in connection with the above-identified application:

Amendments to the Claims are reflected in a listing of the claims, beginning on page 2 of this paper.

Remarks begin on page 7 of this paper.